Atty. Docket No.:

2846/2112

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

cation of:

Ren et al.

Examiner:

McNeil, Jennifer

Serial No.:

10/660,348

Filed:

September 11, 2003

Entitled:

Metal Oxide Nanostructures with

Hierarchical Morphology

Group Art Unit:

1775

Conf. No.:

5141

CERTIFICATE OF MAILING UNDER 37 C.F.R. § 1.8a

I hereby certify that this correspondence (and any paper or fee referred to as being enclosed) is being deposited with the United States Post Office as First Class Mail on the date indicated below in an envelope addressed to Mail Stop Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

David J. Dykennan

Signature of Person Mail ng Paper

Mail Stop Amendment **Commissioner for Patents** P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR §§§ 1.56, 1.97 AND 1.98

Dear Sir:

In accordance with the duty of disclosure under 37 CFR § 1.56, Applicant submits this Information Disclosure Statement pursuant to 37 CFR §§ 1.97 and 1.98 in the above-identified application for consideration by the Patent Office.

A listing of the cited documents, as well as, for the Examiner's convenience, copies of all foreign patent documents and non-patent literature are enclosed. This application was filed after June 30, 2003, and copies of U.S. patents and U.S. patent applications are not required and are not enclosed.

Pursuant to CFR § 1.97(e)(1), each item contained in the Information Disclosure Statement was first cited in a communication from a foreign patent office in a counterpart foreign application or International application. Because this statement is being filed within three months of receipt of the Search Report, no fee is believed to be due. A copy of the Search Report is included and cited on the enclosed PTO-1449.

Applicant does not intend to represent that any of the documents submitted herein are material prior art to this invention or that the list represents an exhaustive search of documents related to this invention.

Date: June 30, 2005

Respectfully submitted.

Name: David J. Dykeman Registration No.: 46,678 Customer No.: 29932 Palmer & Dodge LLP 111 Huntington Avenue Boston, MA 02199-7613

Tel: 617-239-0100

USPTO Form 1449 Serial No. Attorney Docket No. Patent and Trademark Office 10/660,348 2846/2112 INFORMATION DISCLOSURE STATEMENT Applicant(s): Ren et al. Filing Date: Setpember 11, 2003 Group: 1775 U.S. PATENT DOCUMENTS Filing Date Class Subclas Examiner Patent No. Date Name Initial (if appropriate) S February 15, 2005 Alivisatos et al. 117 68 November 20, 2002 6,855,202 428 37 January 13, 2004 6,863,943 March 8, 2005 Wang et al. FOREIGN PATENT DOCUMENTS Document No. Publication Class Subclas Translation Examiner Country Initial Date YES NO OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.) International Search Report based on PCT/US03/28530 dated April 7, 2005. DATE CONSIDERED **EXAMINER** *EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.

JUL 0 5 2005

**Copies of references not provided at the time of this submission.

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Signature of Person Mailing

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Applicant does not intend to represent that any of the documents submitted herein are material prior art to this invention or that the list represents an exhaustive search of documents related to this invention.

Applicant respectfully requests that the documents submitted herein be considered and made of record in this application.

Pursuant to CFR § 1.97(c)(2), because this Statement is being submitted after the mailing of the first Office Action on the merits, the Commissioner for Patents is hereby authorized to charge any fees to Deposit Account No. 16-0085, Reference 2846/2112.

Date: June 30, 2005

Name: David J. Dykaman

Registration No.: 46,678 Customer No.: 29932

Palmer & Dodge LLP 111 Huntington Avenue

Respectfully submitted

Boston, MA 02199-7613 Tel: 617-239-0100

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| | | | | Applicant(s): Ren et al. | | | | | |
| | | | | Filing Date: September 11, 2003 | | | Group: 1775 | | |
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| next communication to Applicant. | | | | | | | | | |